## Journal of Materials Chemistry C



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## CORRECTION

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Cite this: J. Mater. Chem. C, 2021, 9, 2977

## Correction: Large-area printed low-voltage organic thin film transistors *via* minimal-solution bar-coating

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DOI: 10.1039/d1tc90031e

rsc.li/materials-c

Correction for 'Large-area printed low-voltage organic thin film transistors *via* minimal-solution bar-coating' by Sujin Sung *et al., J. Mater. Chem. C*, 2020, **8**, 15112–15118, DOI: 10.1039/D0TC03089A.

The authors wish to include an additional funding number in the Acknowledgements section of this article. The corrected Acknowledgements section should read as follows (the new funding number is shown in bold type):

This work was supported by the National Research Foundation (NRF) grant funded by the Korea government (MSIT) (NRF-2018M3A7B4070988, NRF-2020M3D1A1030660, NRF-2020M3D1A1069831, **NRF-2020M1A2A2080748**) and, by GIST Research Institute (GRI) grant funded by the GIST in 2020.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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